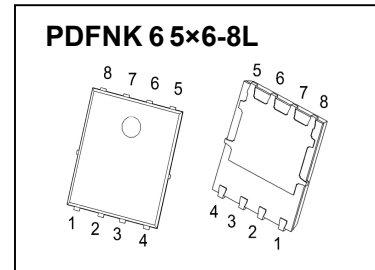




**PDFNK 6 5×6-8L Plastic-Encapsulate MOSFETS**

**CJAC100SN08 N-Channel Power MOSFET**

V <sub>(BR)DSS</sub>	R <sub>DS(on)TYP</sub>	I <sub>D</sub>
80V	2.9mΩ@10V	100A
	4.3mΩ@4.5V	



**DESCRIPTION**

The CJAC100SN08 uses SGT technology and design to provide excellent R<sub>DS(ON)</sub> with low gate charge. It can be used in a wide variety of applications

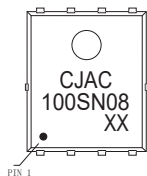
**FEATURES**

- Battery switch
- Load switch
- High density cell design for ultra low R<sub>DS(ON)</sub>
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

**APPLICATIONS**

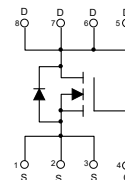
- SMPS and general purpose applications
- Hard switched and high frequency circuits
- Uninterruptible Power Supply

**MARKING**



CJAC100SN08 = Part No.  
 Solid dot = Pin1 indicator  
 XX = Code

**EQUIVALENT CIRCUIT**



**MAXIMUM RATINGS ( T<sub>a</sub>=25°C unless otherwise noted )**

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	80	V
Gate-Source Voltage	V <sub>GS</sub>	+20/-12	V
Continuous Drain Current	I <sub>D</sub> <sup>①</sup>	100	A
Pulsed Drain Current	I <sub>DM</sub> <sup>②</sup>	400	A
Single Pulsed Avalanche Energy	E <sub>AS</sub> <sup>③</sup>	245	mJ
Power Dissipation	P <sub>D</sub> <sup>①</sup>	142	W
Thermal Resistance from Junction to Ambient	R <sub>θJA</sub> <sup>⑥</sup>	62	°C/W
Thermal Resistance from Junction to Case	R <sub>θJC</sub> <sup>①</sup>	0.88	°C/W
Junction Temperature	T <sub>J</sub>	150	°C
Storage Temperature Range	T <sub>stg</sub>	-55 ~+150	°C
Lead Temperature for Soldering Purposes(1/8" from case for 10s)	T <sub>L</sub>	260	°C

# MOSFET ELECTRICAL CHARACTERISTICS

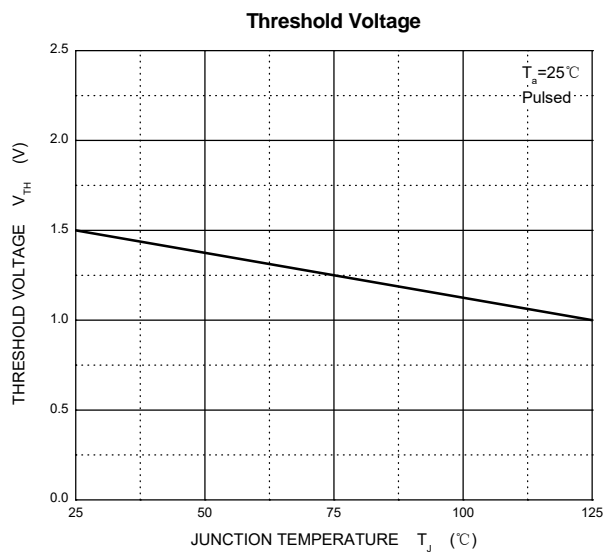
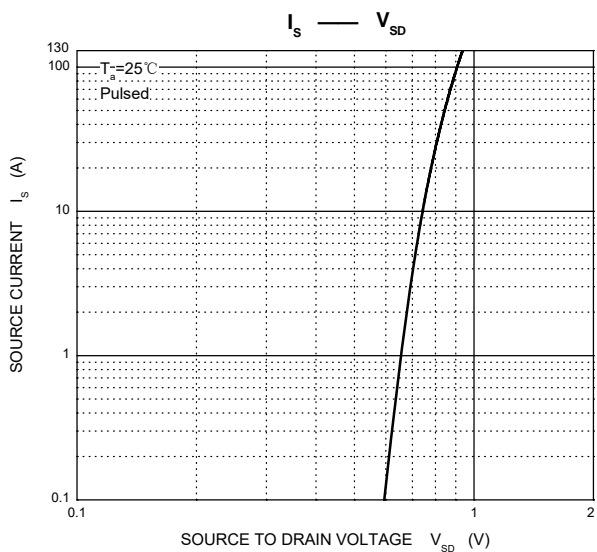
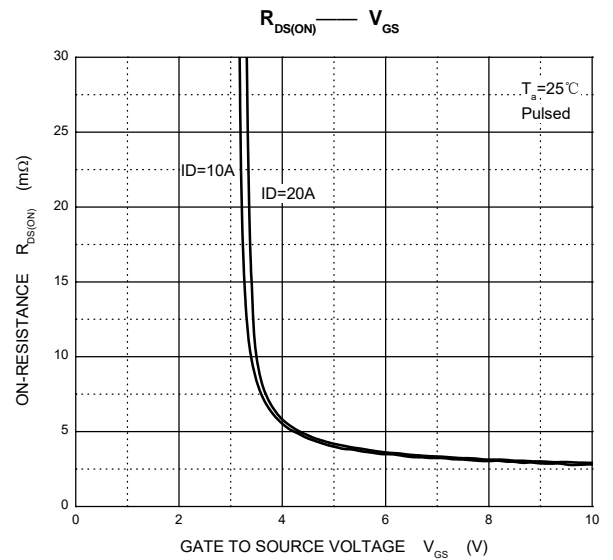
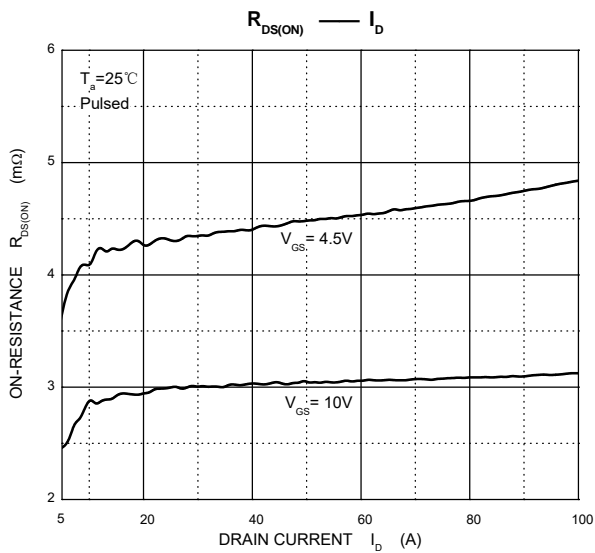
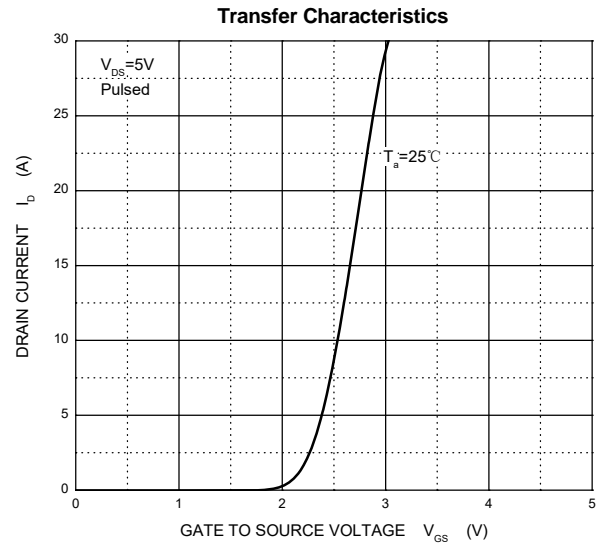
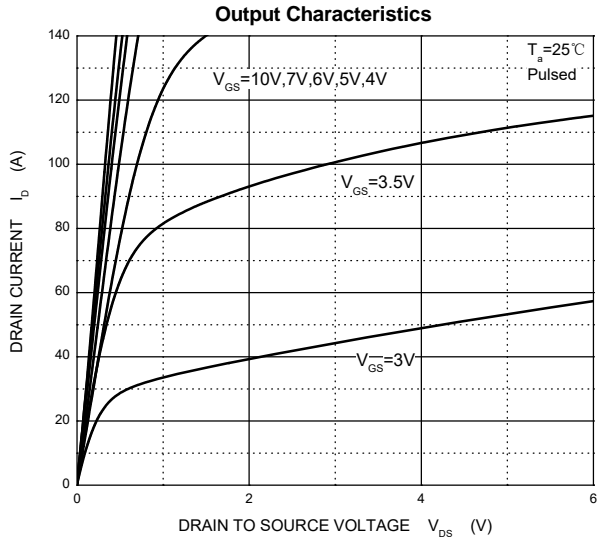
$T_a=25^\circ\text{C}$  unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
<b>Off characteristics</b>						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	80			V
Zero gate voltage drain current	$I_{DSS}$	$V_{DS} = 80V, V_{GS} = 0V$			1	$\mu A$
Gate-body leakage current	$I_{GSS}$	$V_{DS} = 0V, V_{GS} = +20/-12$			$\pm 100$	nA
<b>On characteristics</b> <sup>④</sup>						
Gate-threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	1.0	1.5	2.5	V
Static drain-source on-state resistance	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 20A$		2.9	3.9	$m\Omega$
		$V_{GS} = 4.5V, I_D = 10A$		4.3	6.2	$m\Omega$
Forward transconductance	$g_{FS}$	$V_{DS} = 10V, I_D = 5A$		18		S
<b>Dynamic characteristics</b> <sup>④ ⑤</sup>						
Input capacitance	$C_{iss}$	$V_{DS} = 25V, V_{GS} = 0V,$ $f = 1MHz$		5310	10200	pF
Output capacitance	$C_{oss}$			1870	2700	
Reverse transfer capacitance	$C_{rss}$			40	80	
Gate resistance	$R_g$	$f = 1MHz$		1.6		$\Omega$
<b>Switching characteristics</b> <sup>④ ⑤</sup>						
Total gate charge	$Q_g$	$V_{GS} = 10V, V_{DS} = 64V,$ $I_D = 10A$		102	132	nC
Gate-source charge	$Q_{gs}$			10	15	
Gate-drain charge	$Q_{gd}$			28	32	
Turn-on delay time	$t_{d(on)}$	$V_{DS} = 40V, I_D = 1A$ $V_{GS} = 10V, R_G = 6\Omega$		20	40	ns
Turn-on rise time	$t_r$			13	26	
Turn-off delay time	$t_{d(off)}$			36	72	
Turn-off fall time	$t_f$			18	36	
<b>Drain-Source Diode Characteristics</b>						
Drain-source diode forward voltage	$V_{SD}$ <sup>④</sup>	$V_{GS} = 0V, I_S = 10A$			1.0	V
Continuous drain-source diode forward current	$I_S$ <sup>①</sup>				100	A
Pulsed drain-source diode forward current	$I_{SM}$ <sup>②</sup>				400	A

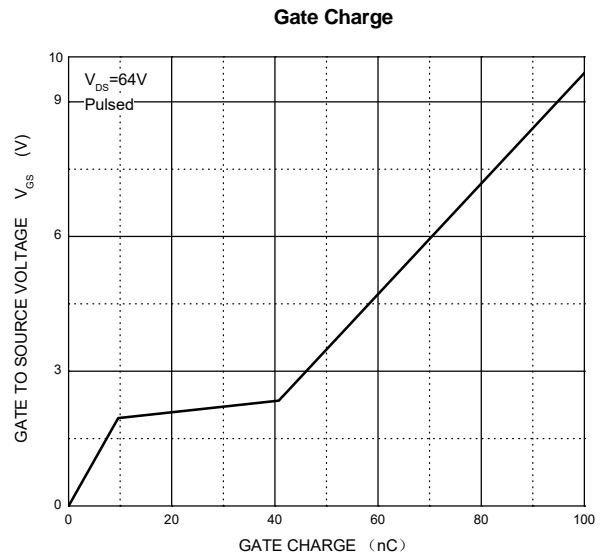
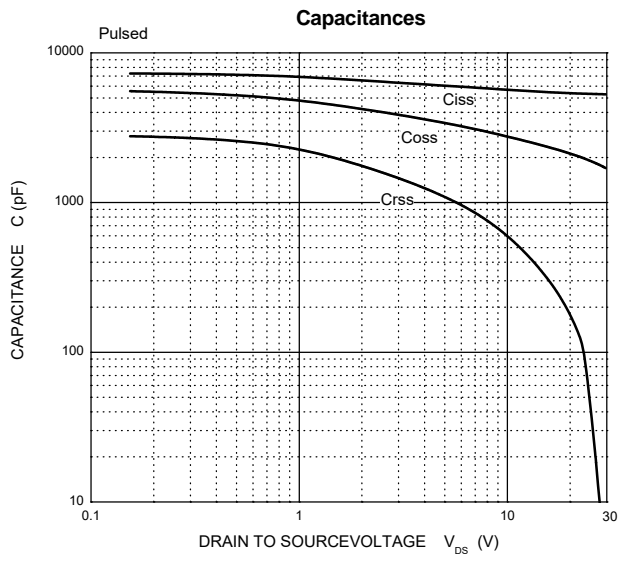
Notes:

- $V_{DM}$  Limited only by maximum temperature allowed.
- $PW \leq 10\mu s$ , Duty cycle  $\leq 1\%$ .
- EAS condition:  $V_{DD} = 30V, V_{GS} = 10V, L = 0.5mH, R_g = 25\Omega$  Starting  $T_J = 25^\circ C$ .
- Pulse Test : Pulse Width  $\leq 300\mu s$ , duty cycle  $\leq 2\%$ .
- Guaranteed by design, not subject to production.
- The value of  $R_{\theta JA}$  is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with  $T_a = 25^\circ C$ .

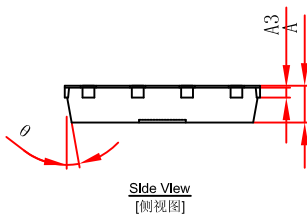
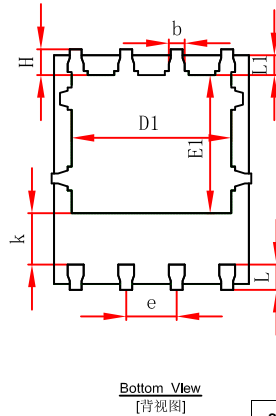
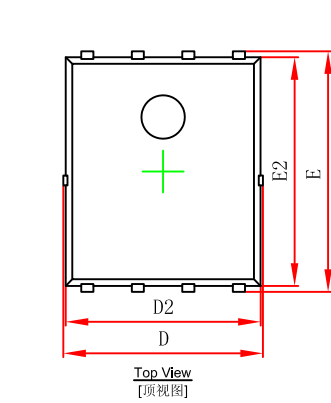
# Typical Characteristics



# Typical Characteristics

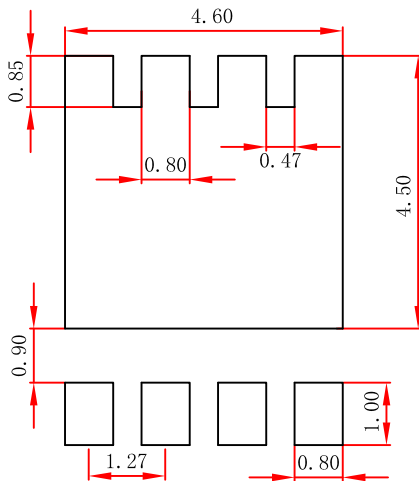


## PDFNWB5x6-8L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.000	0.035	0.039
A3	0.254REF.		0.010REF.	
D	4.944	5.096	0.195	0.201
E	5.974	6.126	0.235	0.241
D1	3.910	4.110	0.154	0.162
E1	3.375	3.575	0.133	0.141
D2	4.824	4.976	0.190	0.196
E2	5.674	5.826	0.223	0.229
k	1.190	1.390	0.047	0.055
b	0.350	0.450	0.014	0.018
e	1.270TYP.		0.050TYP.	
L	0.559	0.711	0.022	0.028
L1	0.424	0.576	0.017	0.023
H	0.574	0.726	0.023	0.029
θ	10°	12°	10°	12°

## PDFNWB5x6-8L Suggested Pad Layout



### Note:

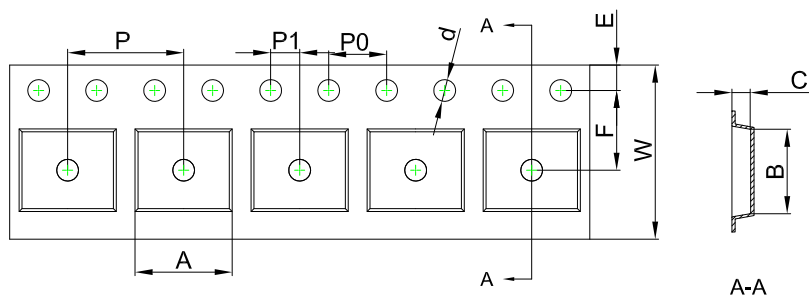
1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.

### NOTICE

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# PDFNWB5×6 Tape and Reel

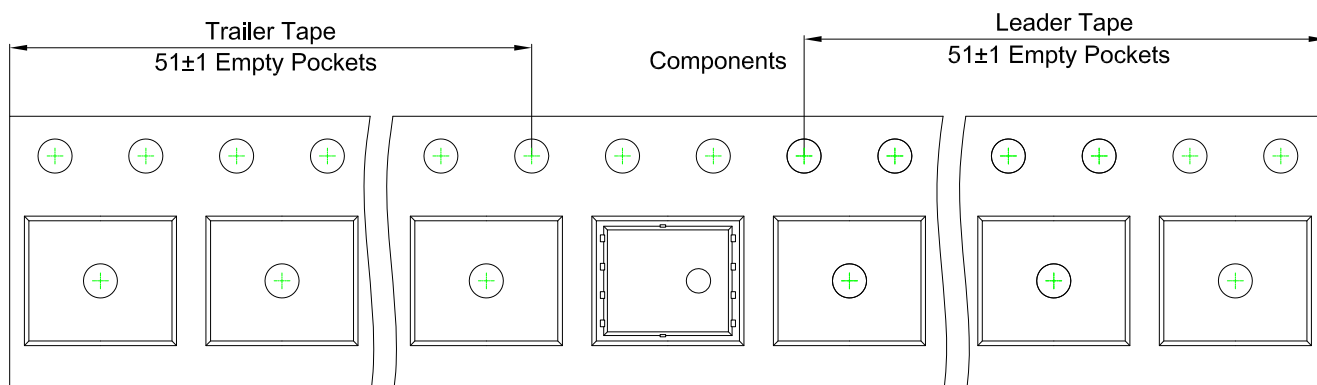
## PDFNWB5×6-8L Embossed Carrier Tape



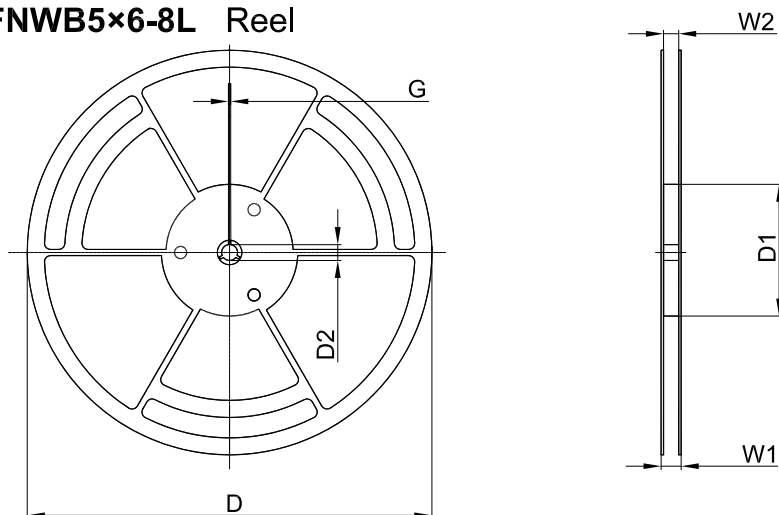
**Packaging Description:**  
**PDFNWB5×6-8L** parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 5,000 units per 13" or 33.0 cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
PDFNWB5×6-8L	6.30	5.30	1.10	Ø1.50	1.75	5.50	4.00	8.00	2.00	12.00

## PDFNWB5×6-8L Tape Leader and Trailer



## PDFNWB5×6-8L Reel



Dimensions are in millimeter						
Reel Option	D	D1	D2	G	W1	W2
13"Dia	Ø330.00	100.00	13.00	1.90	17.60	12.40

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)
5,000 pcs	13 inch	5,000 pcs	340×336×29	50,000 pcs	353×346×365

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